

## Product Features

3.1-3.5GHz:>450W, pulsed CW

>55% Drain Efficiency@50V

50ohm in and out, screw down

Device used: STBV35450BY2

## Applications

5G Power amplifier

S band communication

ISM

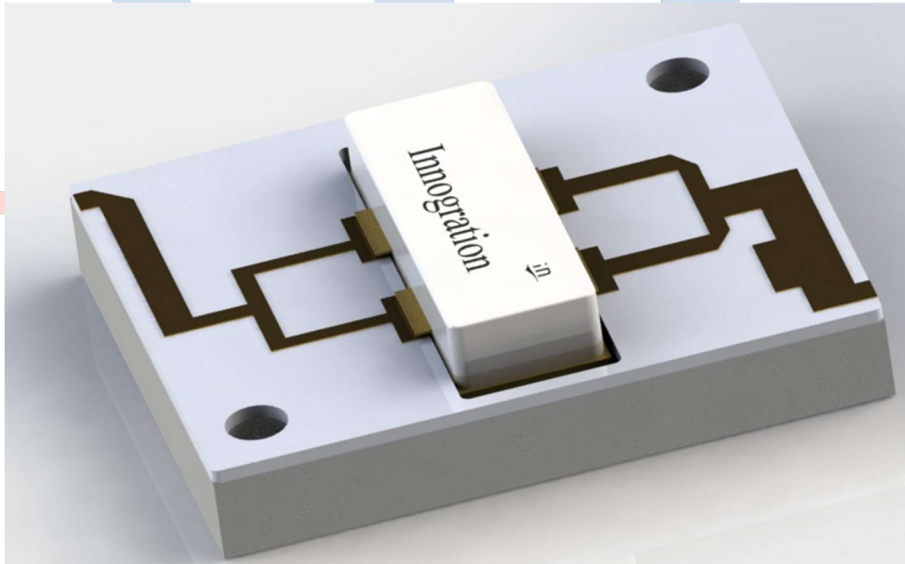
Commercial pulsed CW Power amplifier

## Description

The SMPA3135-450V is designed for 5G communication, test and measurement and other ISM applications at 3100-3500MHz. This Amplifier pallet is suitable for use in linear and saturated applications. Featured by 50ohm fully matched at input and output, drop-in placement by screwing it down and 100% RF test, it enables easier power combination to reach higher power with high production yield as part of customer's power amplifier system.

**This standard pallet is with typical size 50\*90mm, but can be shrunk to much smaller size.**

*Pallet concept demostration purpose only, Not exactly the design itself*





**Electrical Specifications @VCC=50V, T=25°C, 50Ωsystem**

PARAMETER	UNIT	MIN	TYP	MAX	SYMBOL
Operating Frequency	MHz	3100	-	3500	fo
Operating Bandwidth	MHz	400		-	OBW
Pulse CW Output Saturated Power	W	450		-	Psat
Power Gain	dB		10	-	G <sub>P</sub>
Gain Flatness	dB	-	-	±0.5	G <sub>F</sub>
Input Return Loss	dB	-4	-	-10	S <sub>11</sub>
Operating Voltage	V	48	50	55	V <sub>DS</sub>
Quiescent Current	mA	-	100	-	I <sub>DQ</sub>
Efficiency@Psat	%		55		Eff

**Environmental Characteristics**

PARAMETER	UNIT	MIN	TYP	MAX	SYMBOL
Operating Case Temperature	°C	-40	-	60	Ta
Storage Temperature	°C	-40		100	Tstg
Relative humidity w/o condensation	%	-	-	95	RH

**Mechanical Specifications**

PARAMETER	UNIT	VALUE
Dimensions(L × W × H)	mm	50×90×4
RF Input Connector	-	N/A
RF Output Connector	-	N/A
Cooling	-	External Heat-sink

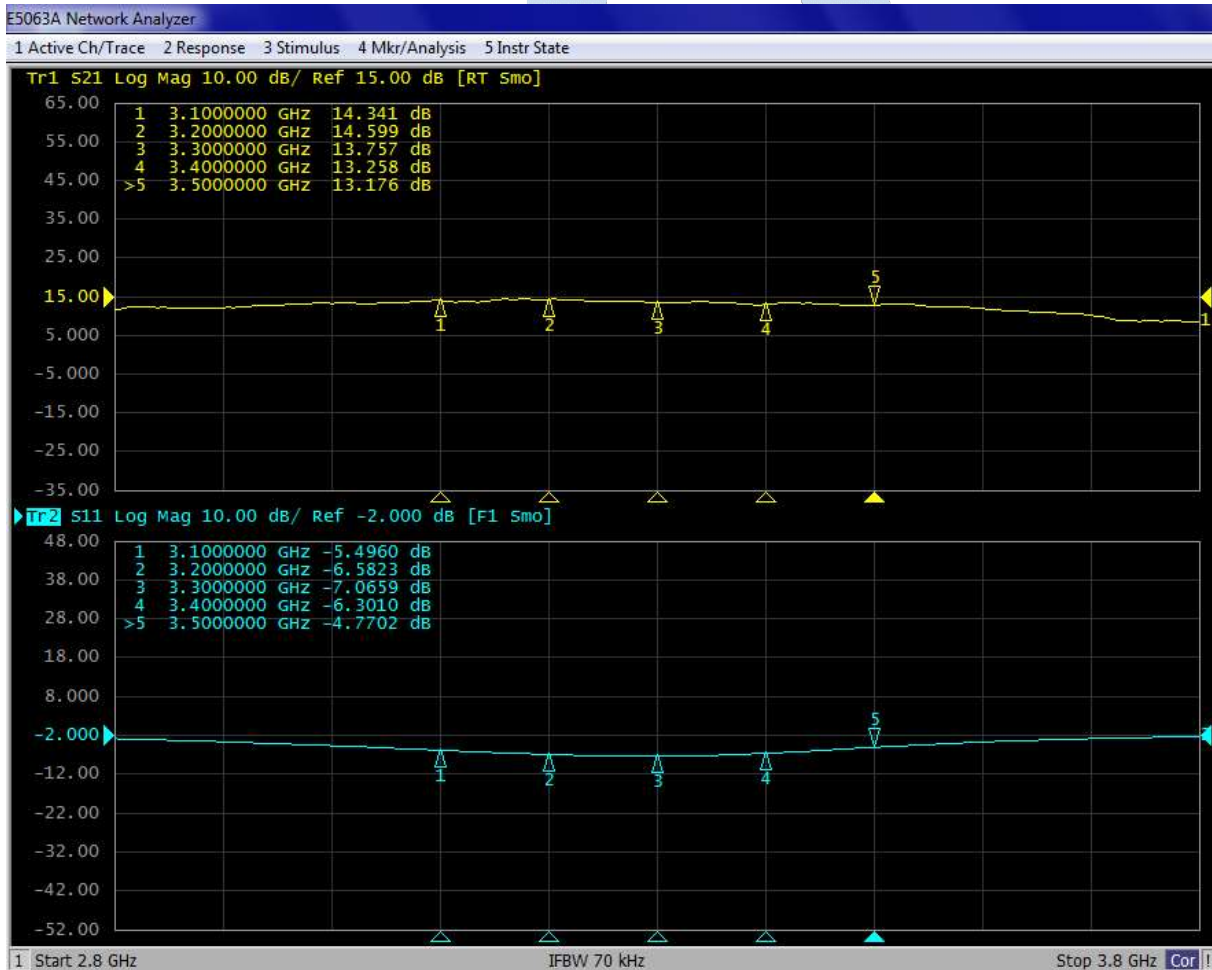


Typical performance

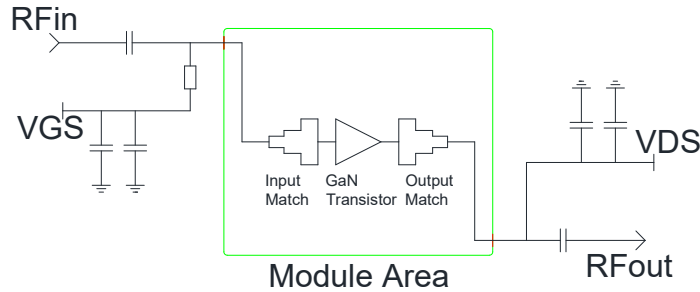
Pulsed CW performance:

STBV35450BY2 V0 Vds=50V,Vgs=-3.43V,Idq=100mA Pulse:100us,10%							
Freq (MHz)	P1dB (dBm)	P1dB (W)	P1dB Eff(%)	P1dB Gain(dB)	P3dB (dBm)	P3dB (W)	P3dB Eff(%)
3100	55.6	360.3	50.6	12.4	56.9	491.9	55.1
3200	55.4	344.2	51.2	12.6	56.9	488.2	56.2
3300	55.6	363.7	50.2	12.8	57.2	518.4	55.2
3400	55.8	383.5	52.0	13.0	57.5	563.7	58.1
3500	54.9	309.6	48.5	12.5	56.7	471.7	55.3

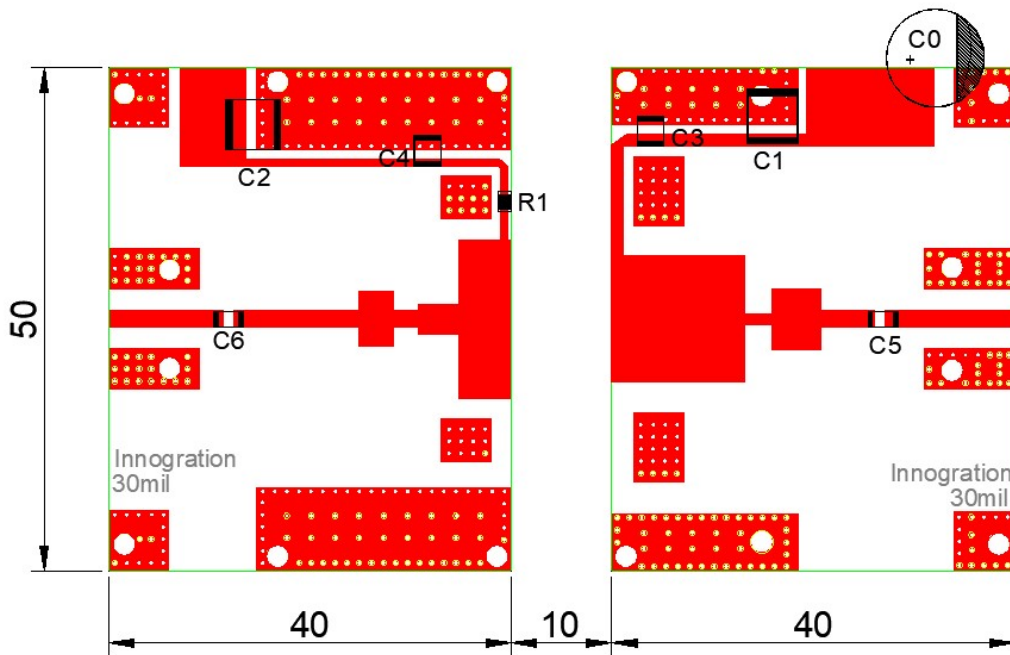
S21/S11 from network analyzer VDS=50V VGS=-3.02V IDQ=500mA



Evaluation board Block Diagram



Evaluation board outline (DUT:STBV35450BY2)



Component	Description	Suggestion
C0	470uF/63V	
C1,C2	10uF	5750
C3,C4	10pF	MQ101111
C5,C6	10pF	MQ301111
R1	Chip Resistor,10Ω	0805
PCB	30 Mil Rogers 4350B	



## Revision History

Document revision history

Date	Revision	Datasheet Status
2023/7/7	Rev 1.0	Preliminary Datasheet

Application data based on RXT-23-28



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